

## IMX2

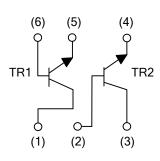
### DUAL TRANSISTOR

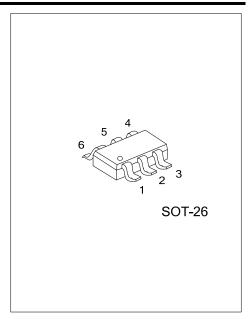
# NPN GENERAL PURPOSE DUAL TRANSISTOR

#### FEATURES

\* Two independently operating NPN transistors.

EQUIVALENT CIRCUITS





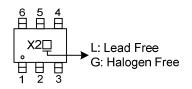
#### ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment					Deeking	
Lead Free	Halogen Free	Package	1	2	3	4	5	6	Packing
IMX2L-AG6 -R	IMX2G-AG6-R	SOT-26	C1	B2	C2	E2	E1	B1	Tape Reel
Note: Pin Assignment: B: Base C: Collector E: Emitter									
IMX2L- <u>AG6</u> -R									
	(1)Packing Type		(1) R: Tape Reel						
	— (2)Package Type	(2) AG6	6: SO	T-26					

(3)Lead Free

(3) G: Halogen Free, L: Lead Free

#### MARKING



#### ■ ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub>=25°C)

PARAMETER	SYMBOL	RATING	UNIT
Collector-Base Voltage	V <sub>CBO</sub>	60	V
Collector-Emitter Voltage	V <sub>CEO</sub>	50	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Collector Current	Ιc	150	mA
Collector Power Dissipation	Pc	300 (Note1)	mW
Junction Temperature	TJ	150	°C
Storage Temperature	T <sub>STG</sub>	-55~+150	۵°

Note: 1. 200mW per element must not be exceeded.

2. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

#### ■ ELECTRICAL CHARACTERISTICS (T<sub>A</sub>=25°C)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Collector-Base Breakdown Voltage	ВV <sub>сво</sub>	I <sub>C</sub> = 50μA	60			V	
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	I <sub>C</sub> = 1mA	50			V	
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	I <sub>E</sub> = 50μA	7			V	
Collector Cut-Off Current	I <sub>CBO</sub>	V <sub>CB</sub> = 60V			0.1	μA	
Emitter Cut-Off Current	I <sub>EBO</sub>	V <sub>EB</sub> = 7V			0.1	μA	
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	$I_C / I_B = 50 \text{mA}/5 \text{mA}$			0.4	V	
DC Current Transfer Ratio	h <sub>FE</sub>	$V_{CE}$ = 6V, I <sub>C</sub> = 1mA	120		560		
Transition Frequency (Note)	f⊤	V <sub>CE</sub> =12V, I <sub>E</sub> =-2mA, f=100MHz		180		MHz	
Output Capacitance	COB	V <sub>CB</sub> = 12V, I <sub>E</sub> =0A, f=1KHz		2	3.5	рF	
Nata: Transition fraguency of the device							

Note: Transition frequency of the device.



UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.

